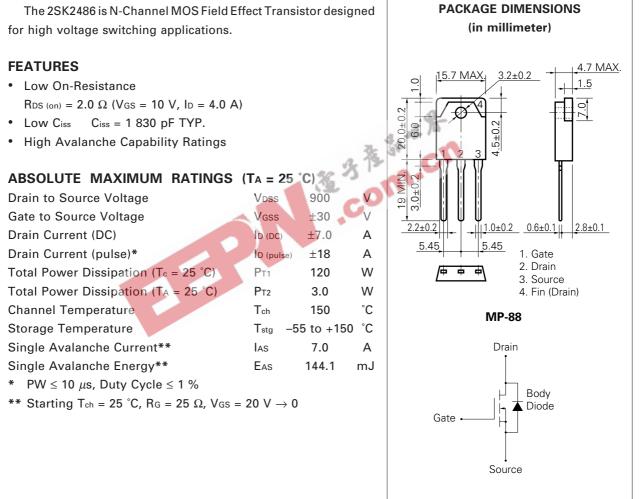
# DATA SHEET



# MOS FIELD EFFECT TRANSISTOR 2SK2486

## SWITCHING N-CHANNEL POWER MOS FET INDUSTRIAL USE

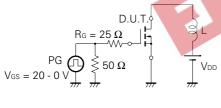
#### DESCRIPTION

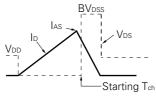


ELECTRICAL	CHARACTERISTICS	(TA = 25 °C)
------------	-----------------	--------------

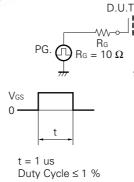
CHARACTERISTIC	SYMBOL	MIN.	TYP.	MAX.	UNIT	TEST CONDITIONS
Drain to Source On-Resistance	RDS (on)		1.4	2.0	Ω	$V_{GS} = 10 V, I_{D} = 4.0 A$
Gate to Source Cutoff Voltage	VGS (off)	2.5		3.5	V	$V_{DS} = 10 V, I_{D} = 1 mA$
Forward Transfer Admittance	y <sub>fs</sub>	2.5			S	$V_{DS} = 20 V, I_{D} = 4.0 A$
Drain Leakage Current	IDSS			100	μA	$V_{DS} = V_{DSS}, V_{GS} = 0$
Gate to Source Leakage Current	lgss			±100	nA	$V_{GS} = \pm 30 \text{ V}, \text{ V}_{DS} = 0$
Input Capacitance	Ciss		1 830		pF	Vds = 10 V
Output Capacitance	Coss		250		pF	Vgs = 0
Reverse Transfer Capacitance	Crss		40		pF	f = 1 MHz
Turn-On Delay Time	td (on)		30		ns	ID = 4.0 A
Rise Time	tr		15		ns	$V_{GS} = 10 V$
Turn-Off Delay Time	td (off)		110		ns	Vdd = 150 V
Fall Time	tr		20		ns	$R_G = 10 \Omega$
Total Gate Charge	Q <sub>G</sub>		55		nC	ID = 7.0 A
Gate to Source Charge	Qgs		10		nC	VDD = 450 V
Gate to Drain Charge	Qgd		25	23	nC	Vgs = 10 V
Body Diode Forward Voltage	VF (S-D)		1.0	3	V	IF = 7.0 A, VGS = 0
Reverse Recovery Time	trr		800	00	ns	IF = 7.0 A, VGS = 0
Reverse Recovery Charge	Qrr	4.	4.8		μC	di/dt = 50 A/µs

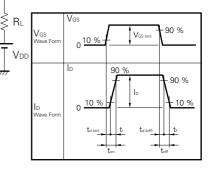
#### Test Circuit 1 Avalanche Capability



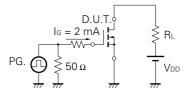


## Test Circuit 2 Switching Time

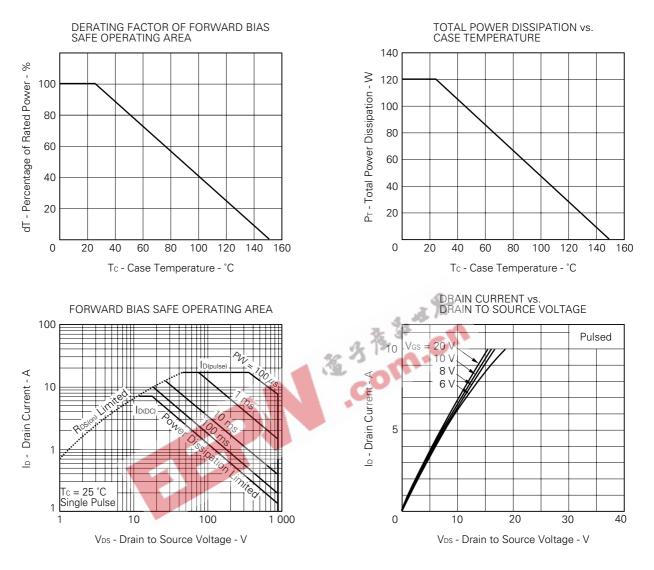




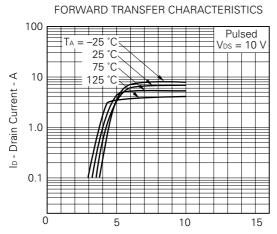
Test Circuit 3 Gate Charge



The application circuits and their parameters are for references only and are not intended for use in actual design-in's.



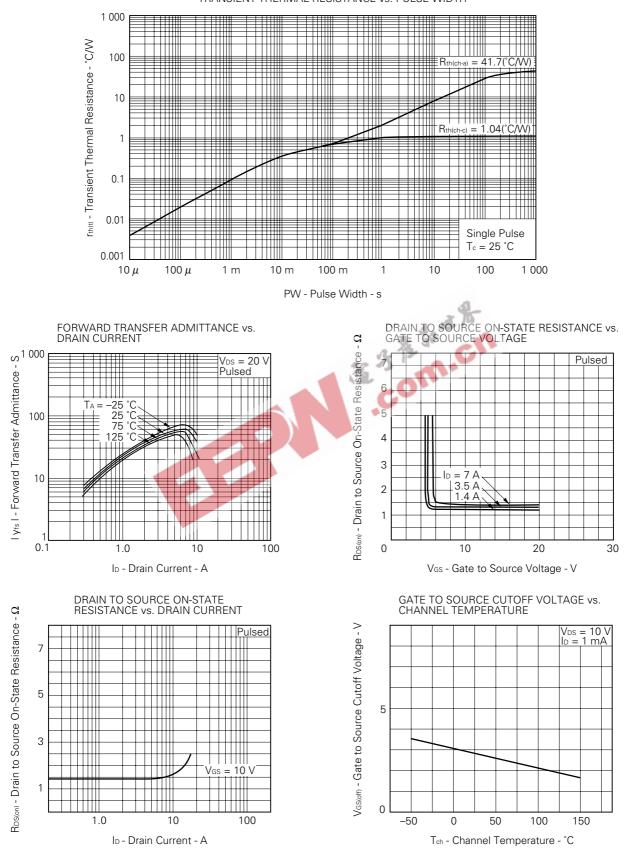
#### **TYPICAL CHARACTERISTICS** (T<sub>A</sub> = 25 $^{\circ}$ C)

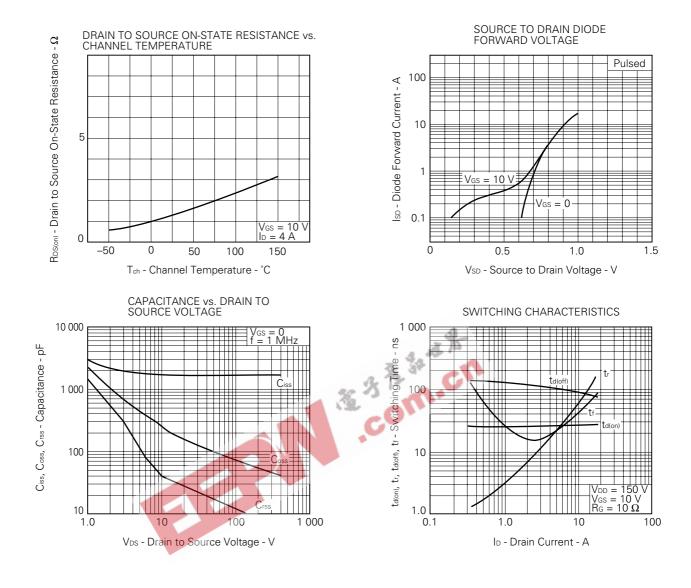


V<sub>GS</sub> - Gate to Source Voltage - V



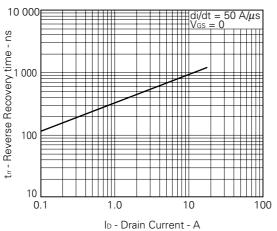
TRANSIENT THERMAL RESISTANCE vs. PULSE WIDTH

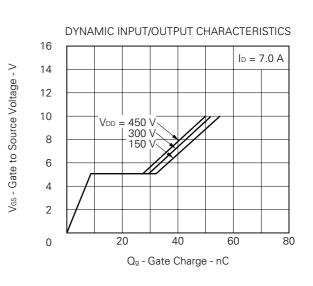


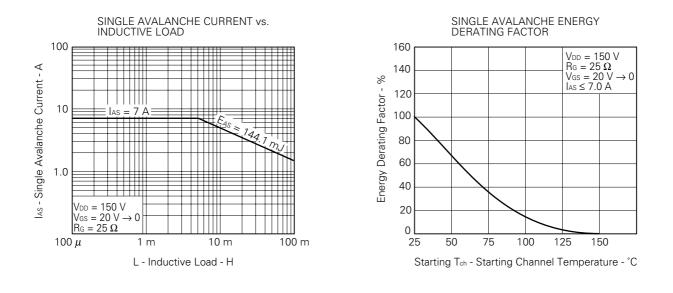




NEC









#### REFERENCE

Document Name	Document No.
NEC semiconductor device reliability/quality control system.	TEI-1202
Quality grade on NEC semiconductor devices.	IEI-1209
Semiconductor device mounting technology manual.	IEI-1207
Semiconductor device package manual.	IEI-1213
Guide to quality assurance for semiconductor devices.	MEI-1202
Semiconductor selection guide.	MF-1134
Power MOS FET features and application switching power supply.	TEA-1034
Application circuits using Power MOS FET.	TEA-1035
Safe operating area of Power MOS FET.	TEA-1037



No part of this document may be copied or reproduced in any form or by any means without the prior written consent of NEC Corporation. NEC Corporation assumes no responsibility for any errors which may appear in this document.

NEC Corporation does not assume any liability for infringement of patents, copyrights or other intellectual property rights of third parties by or arising from use of a device described herein or any other liability arising from use of such device. No license, either express, implied or otherwise, is granted under any patents, copyrights or other intellectual property rights of NEC Corporation or others.

While NEC Corporation has been making continuous effort to enhance the reliability of its semiconductor devices, the possibility of defects cannot be eliminated entirely. To minimize risks of damage or injury to persons or property arising from a defect in an NEC semiconductor device, customer must incorporate sufficient safety measures in its design, such as redundancy, fire-containment, and anti-failure features. NEC devices are classified into the following three quality grades:

"Standard", "Special", and "Specific". The Specific quality grade applies only to devices developed based on a customer designated "quality assurance program" for a specific application. The recommended applications of a device depend on its quality grade, as indicated below. Customers must check the quality grade of each device before using it in a particular application.

Standard: Computers, office equipment, communications equipment, test and measurement equipment, audio and visual equipment, home electronic appliances, machine tools, personal electronic equipment and industrial robots

Special: Transportation equipment (automobiles, trains, ships, etc.), traffic control systems, anti-disaster systems, anti-crime systems, safety equipment and medical equipment (not specifically designed for life support)

Specific: Aircrafts, aerospace equipment, submersible repeaters, nuclear reactor control systems, life support systems or medical equipment for life support, etc.

The quality grade of NEC devices in "Standard" unless otherwise specified in NEC's Data Sheets or Data Books. If customers intend to use NEC devices for applications other than those specified for Standard quality grade, they should contact NEC Sales Representative in advance.

Anti-radioactive design is not implemented in this product.

M4 94.11